

SAMTM Data Sheet SAM-1040-10-1ps-x, λ = 1040 nm

 $\lambda = 1040 \text{ nm}$ Laser wavelength

High reflection band (R > 88%) λ = 1010 .. 1100 nm

Absorbance $A_0 = 10 \%$ Modulation depth $\Delta R = 6 \%$ Non-saturable loss $A_{ns} = 4 \%$

Saturation fluence $\Phi_{\text{sat}} = 35 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 1 \text{ ps}$

 $\Phi = 3 \text{ mJ/cm}^2$ Damage threshold

4 mm x 4 mm; other dimensions on request Chip area

Chip thickness 450 µm; optional: 150 µm on request

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted

glued on a copper heat sink with 12.7 mm \varnothing x = 12.7 gx = 25.4 qglued on a copper heat sink with 25.4 mm Ø x = 12.7 ssoldered on a copper heat sink with 12.7 mm \varnothing soldered on a copper heat sink with 25.4 mm \varnothing x = 25.4 s

x = 25.0 wsoldered on a water cooled copper heat sink with 25.0 mm Ø x = FCmounted on a 1 m single mode fiber with FC connector

Low intensity spectral reflectance and dispersion

